# NSN 5961-00-917-1636

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-917-1636

Inclosure Material:

Metal

**Overall Length:** 

0.375 inches

## **Overall Diameter:**

0.875 inches

# Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

## Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release5031 professional/industrial association specification

#### Shelf Life:

N/a

#### Unit Of Measure:

---

## Demilitarization:

No

## Fiig:

A110a0